D	2016-5				
E	2020-8-14	1			
F	2021-4-26	ALL			

TO-252 N MOS

N-CHANNEL MOSFET in a TO-252 Plastic Package.

, ,

Low gate charge, low crss, fast switching. HF Product.



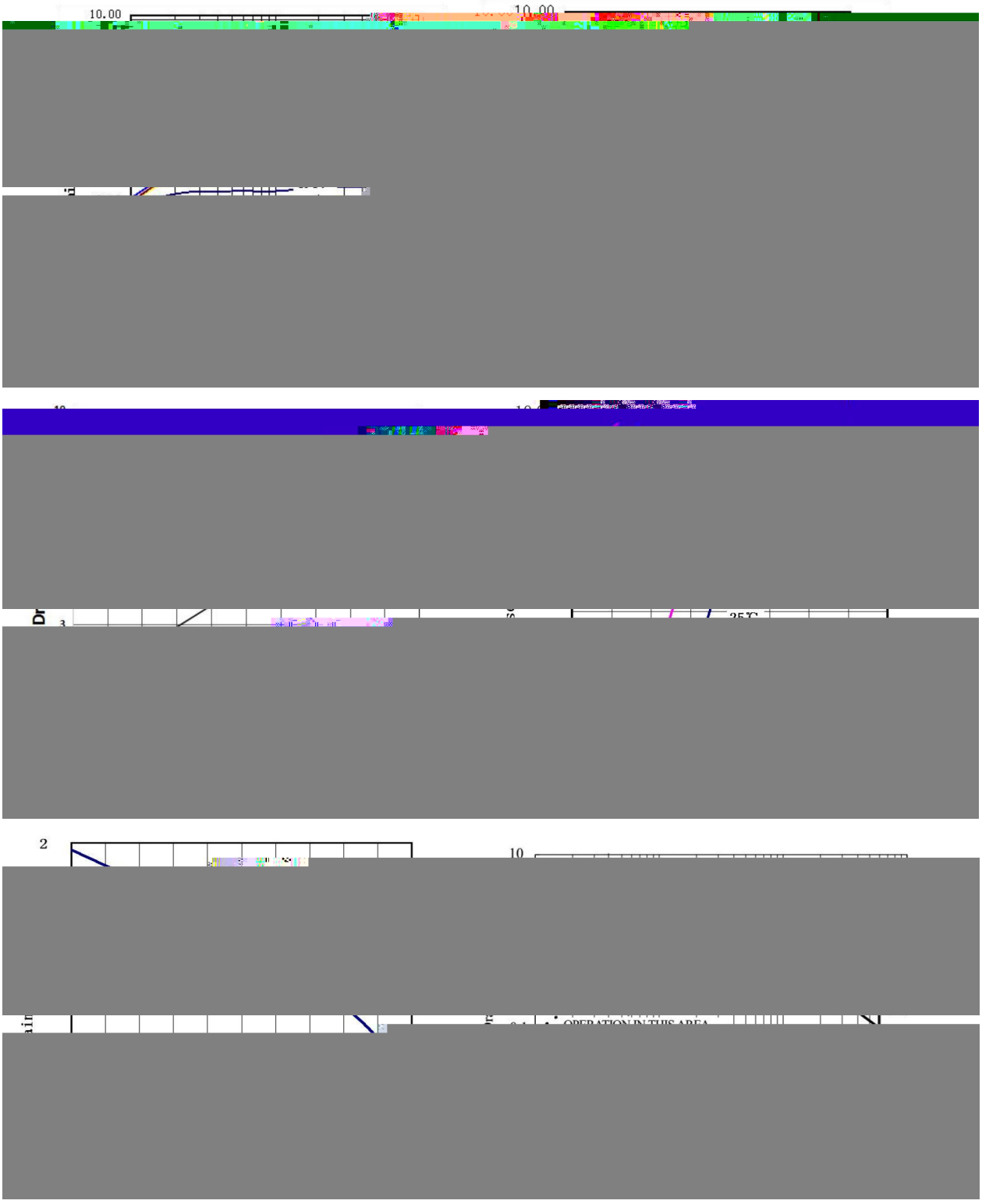
		Rating	Unit
Drain-Source Voltage	V_{DSS}	600	V

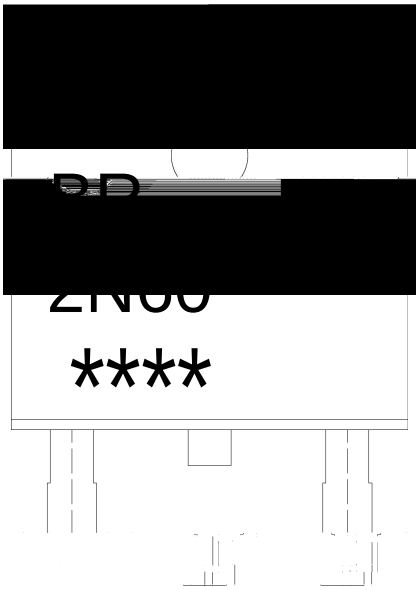
http://www.fsbrec.com /

80402006 Tm BT 10.56 0

6.350.5603 TJ E@m 5S61 0 0 07389641 6m6.9586.38T64.37 m69586516864.37 l 9586516863.738969586.38163.6869443

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Capacitance	C_{iss}	V_{DS}=25V V_{GS}=0V f=1.0MHz		278		pF
Output Capacitance	C_{oss}			20		pF
Reverse Transfer Capacitance	C_{rss}			5		pF
Turn-On Delay Timez u	¥$_{d(on)}$	ضذ V_{DD}=300V I_D=2.0A¶ R_G=25Ω				


10.00
10.00
25°C
2
10
OPERATION IN THIS AREA



BR

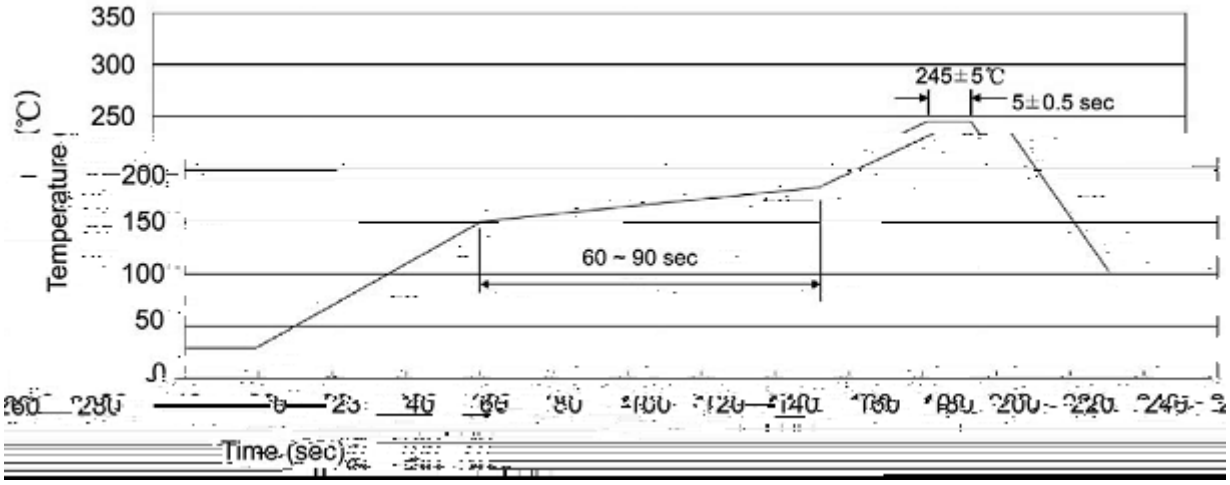
2N60

****

Note:

BR:	Company Code.
2N60:	Product Type.
****:	Lot No. Code, code change with Lot No.

Temperature Profile for IR Reflow Soldering(Pb-Free)



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